

Dual Anode Single Photon Avalanche Diodes for High-Speed Applications

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UNIVERSITÉ
DE GENÈVE

FACULTÉ DES SCIENCES

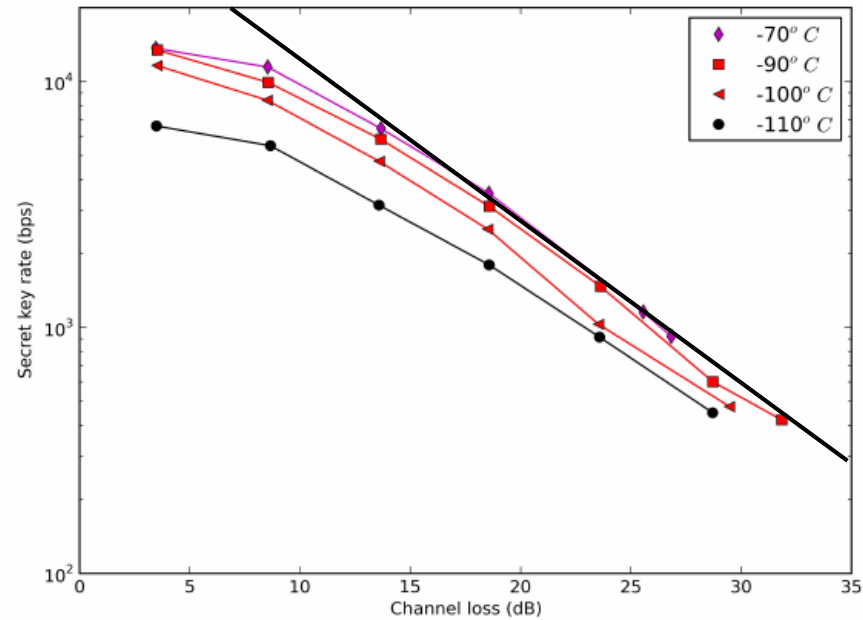
Motivation

→ More compact and easier to use single photon detectors;

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- Improving Secret Key Rate (SKR) in Quantum Key Distribution (QKD) systems

SKR vs Channel Loss (distance) for COW Protocol

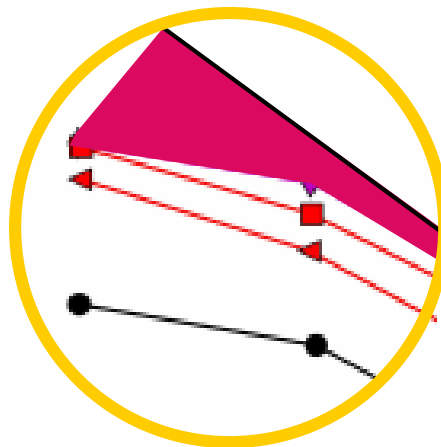
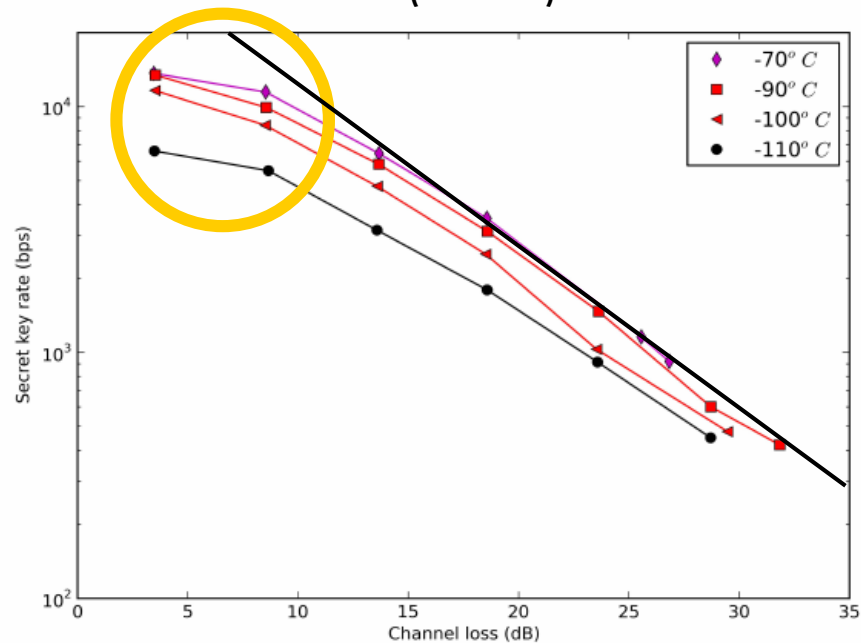


Korzh, Boris & Zbinden, Hugo. (2014). Proceedings of SPIE - The International Society for Optical Engineering. 9114. 10.1117/12.2050487.

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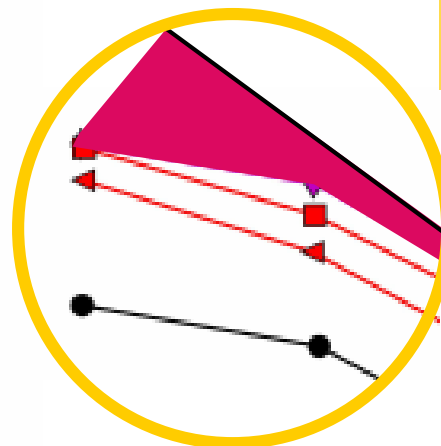
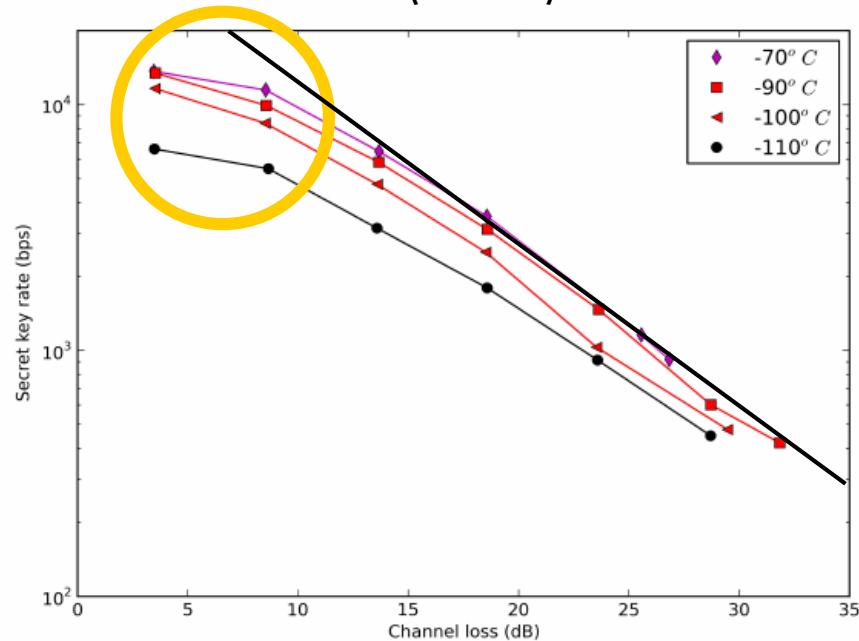
Afterpulsing effect is a critical problem in high speed low noise single photon avalanche diodes (SPADs)

↓
Limits performance of
QKD protocols

Motivation

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SKR vs Channel Loss (distance) for COW Protocol



A detection is registered as a result of a previous detection, even if no light arrives.

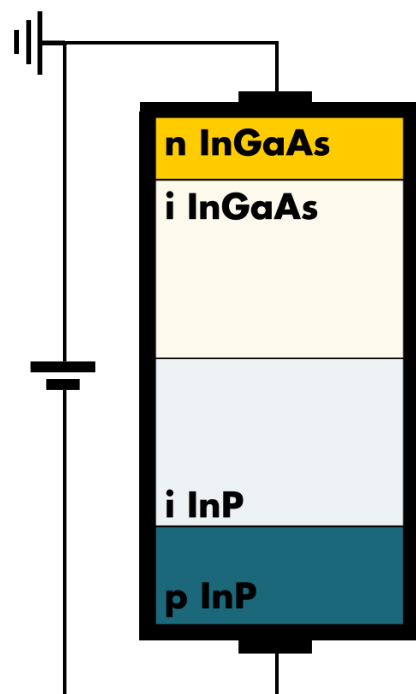
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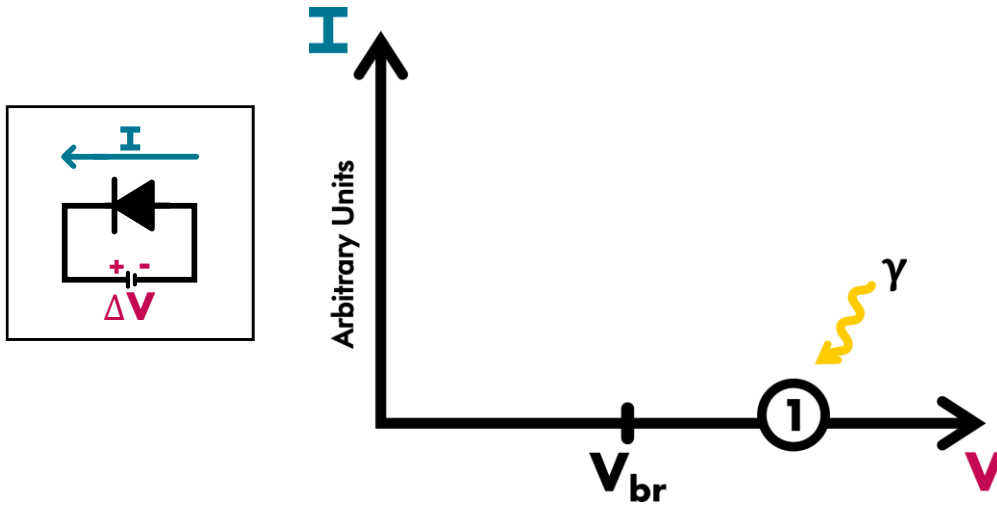
What is a SPAD?

SPAD – **S**ingle **P**hoton **A**valanche **D**iode

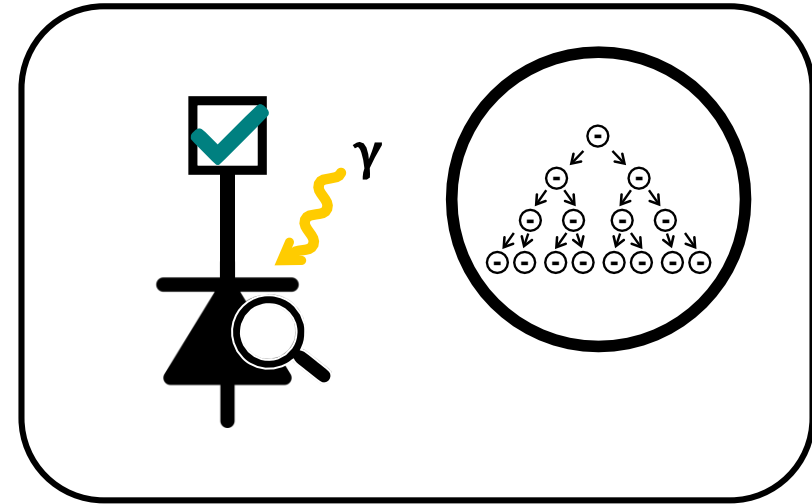
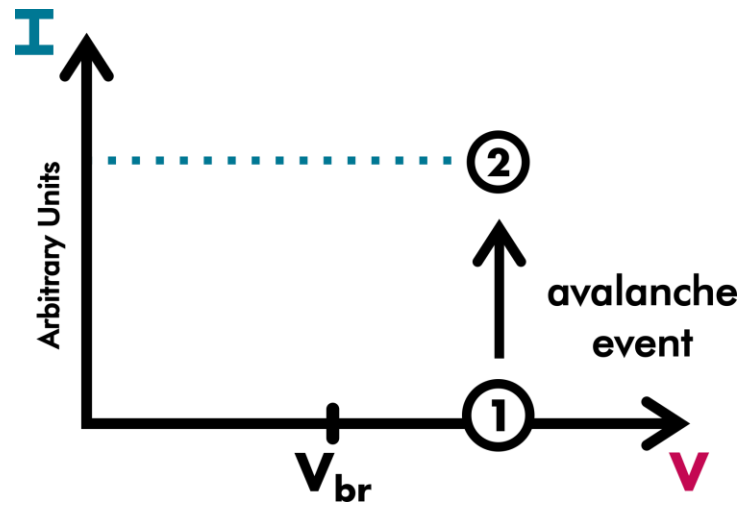
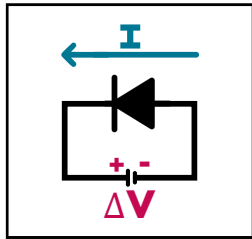
p – n / p – i – n Junction



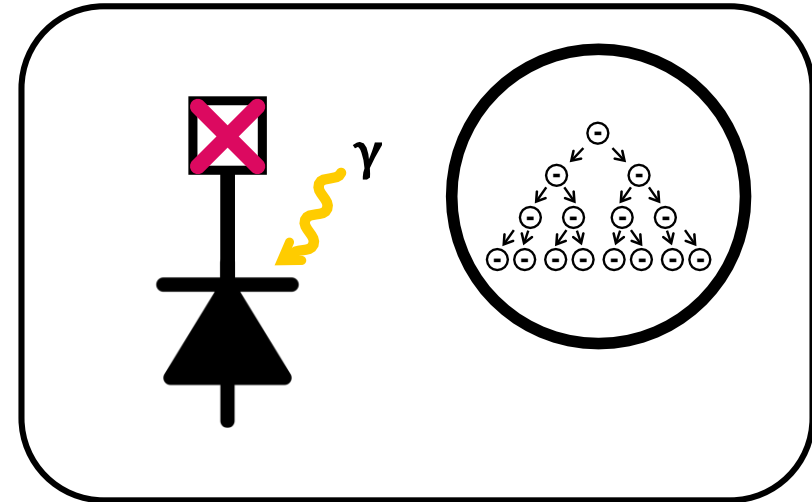
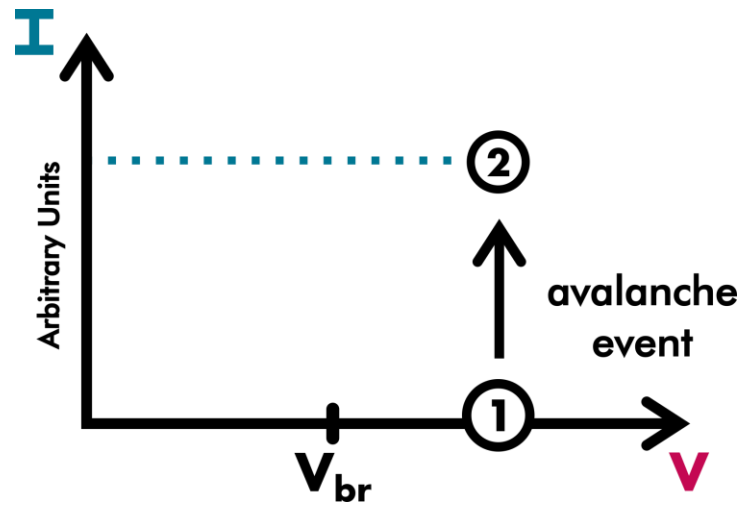
How does a SPAD work?



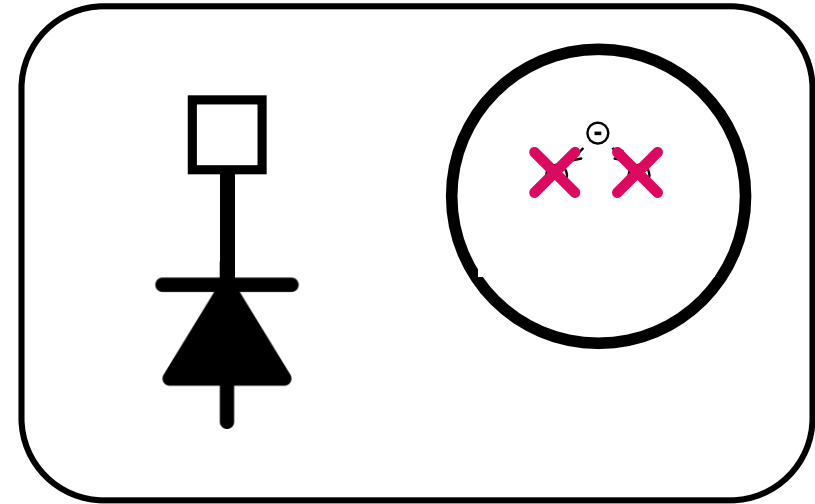
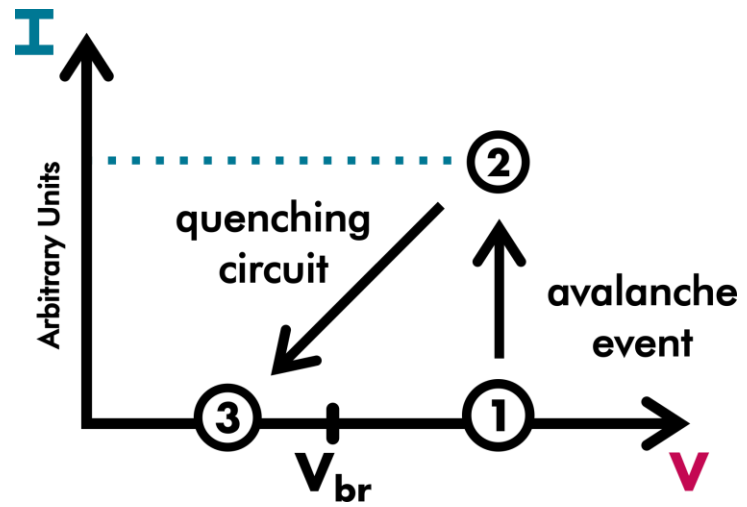
How does a SPAD work?



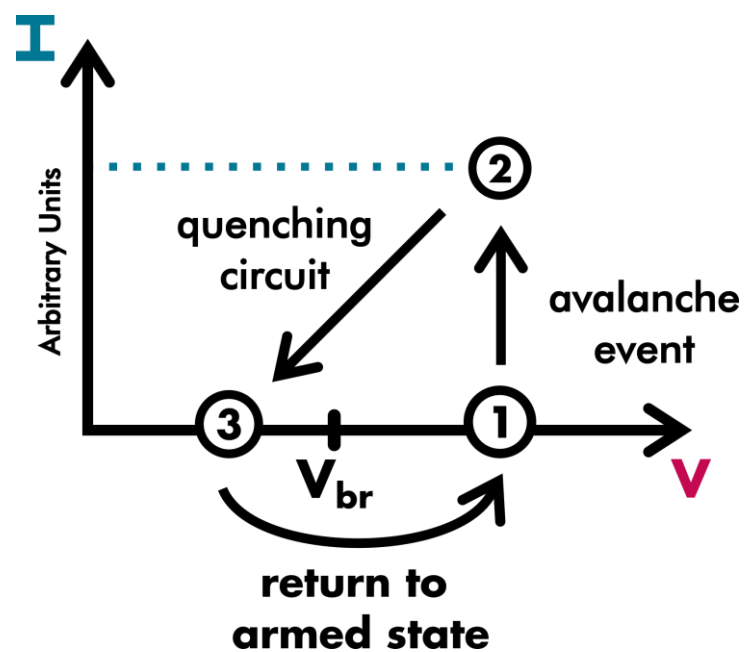
How does a SPAD work?



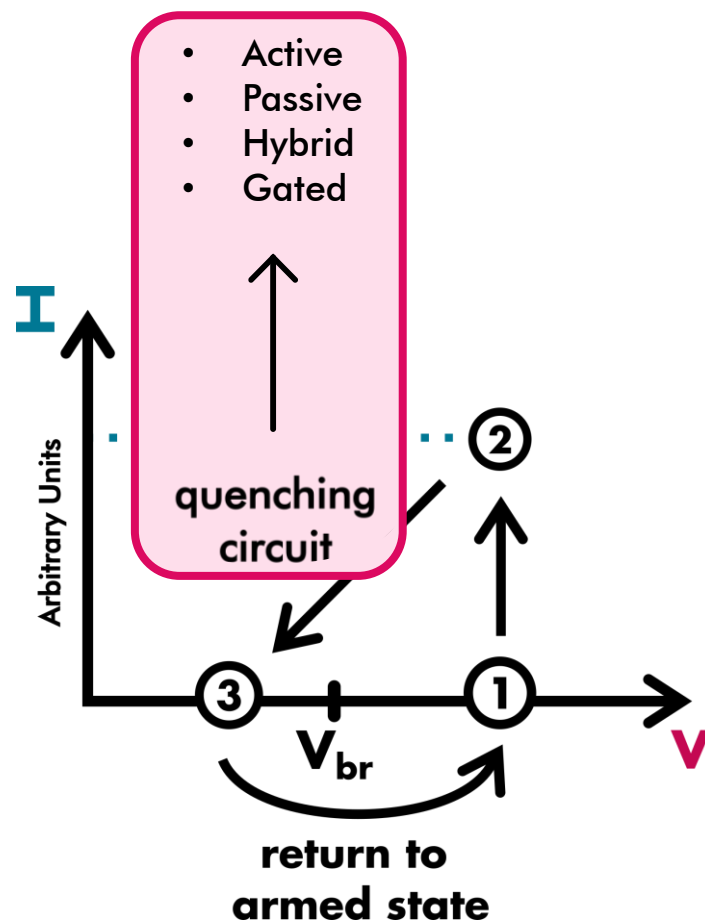
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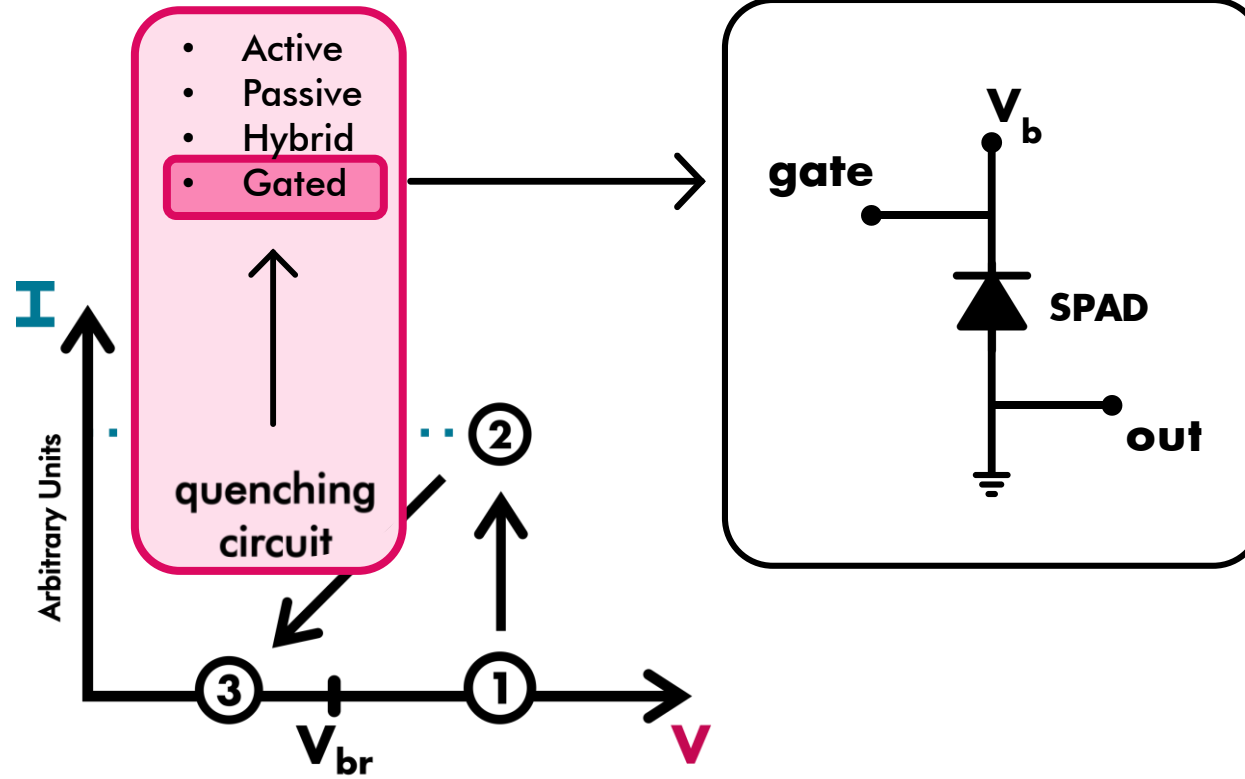
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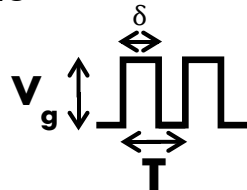


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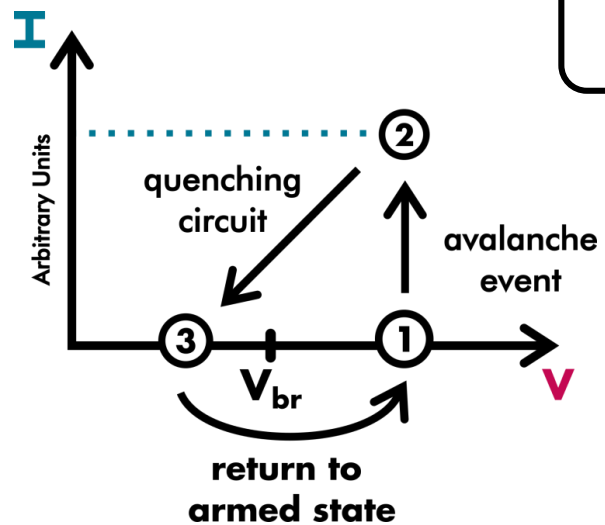
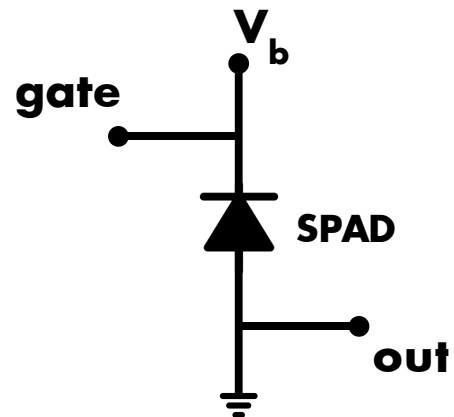
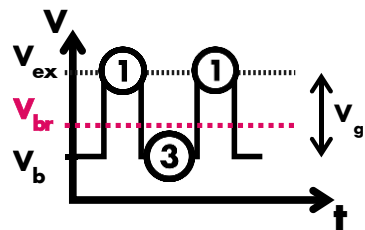


How does a SPAD work?

gate

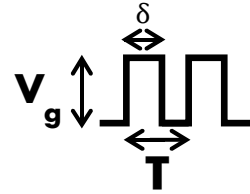


SPAD

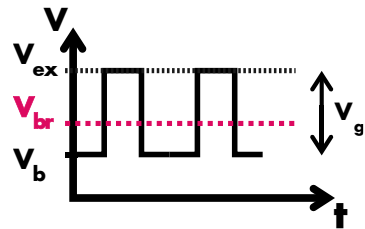


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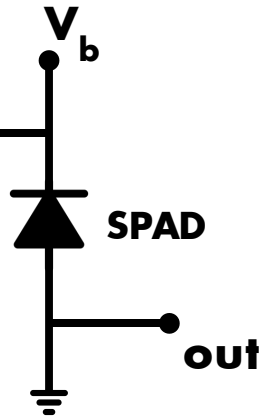
gate



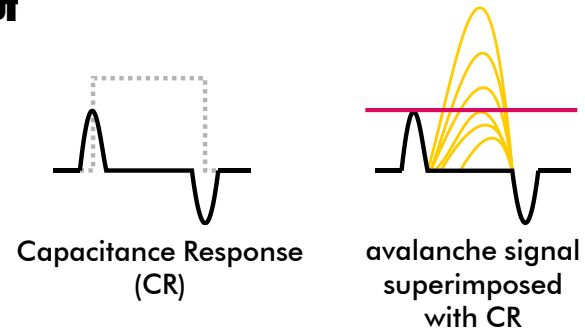
SPAD



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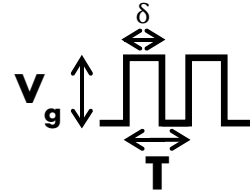


out

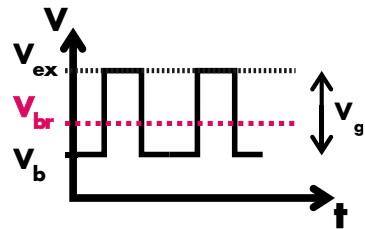


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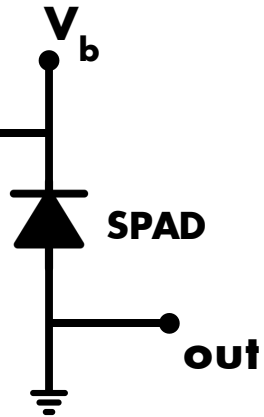
gate



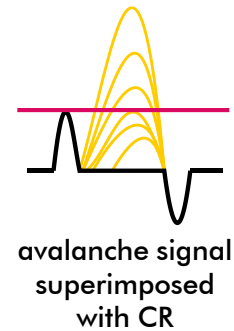
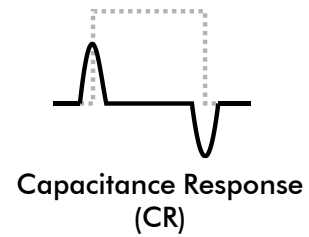
SPAD



gate



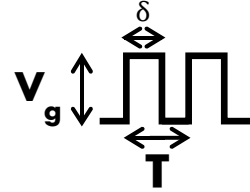
out



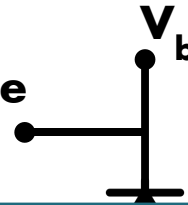
Afterpulsing effect is worse for bigger avalanches.

How does a SPAD work?

gate

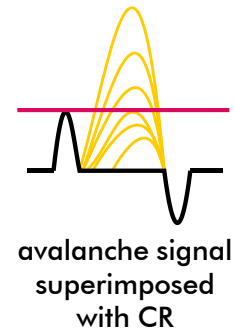
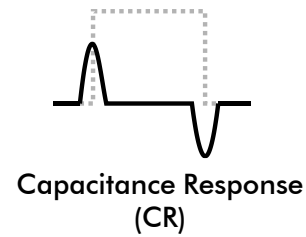


gate



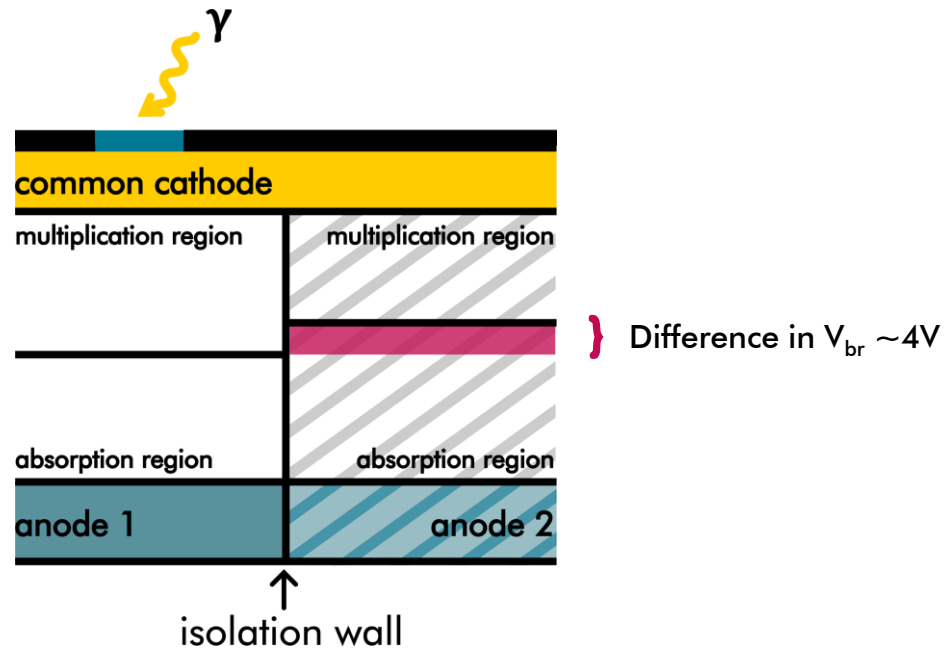
Goal: minimize CR to allow the discrimination of the smallest possible avalanche events, to improve count rate.

out

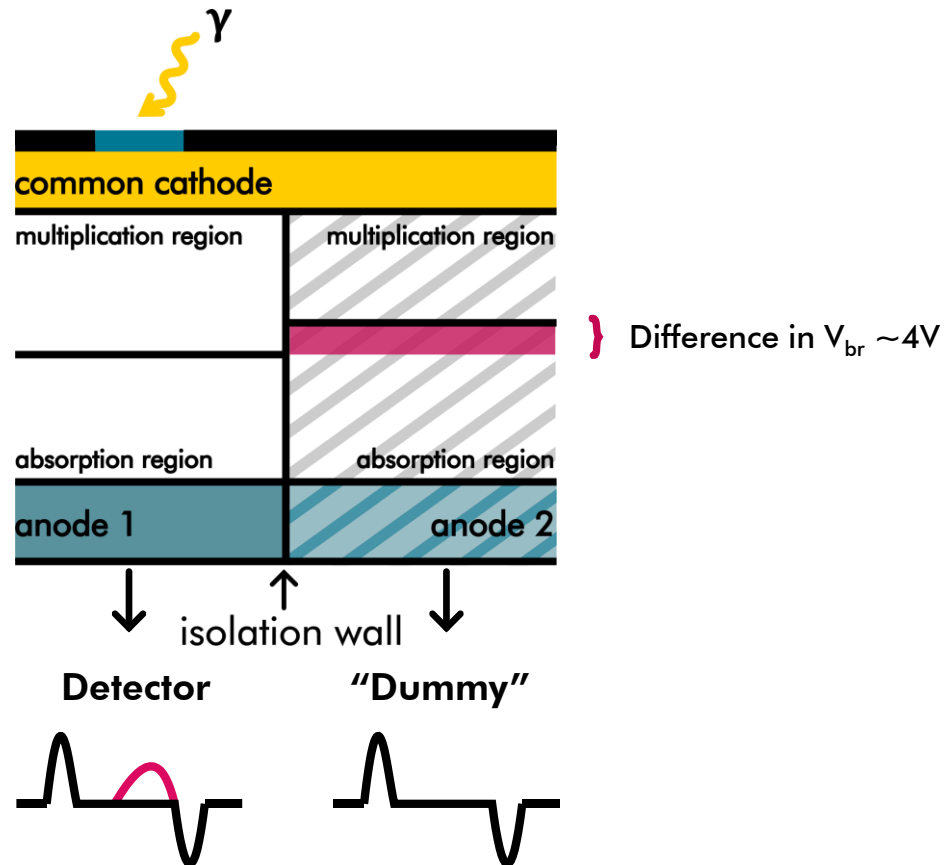


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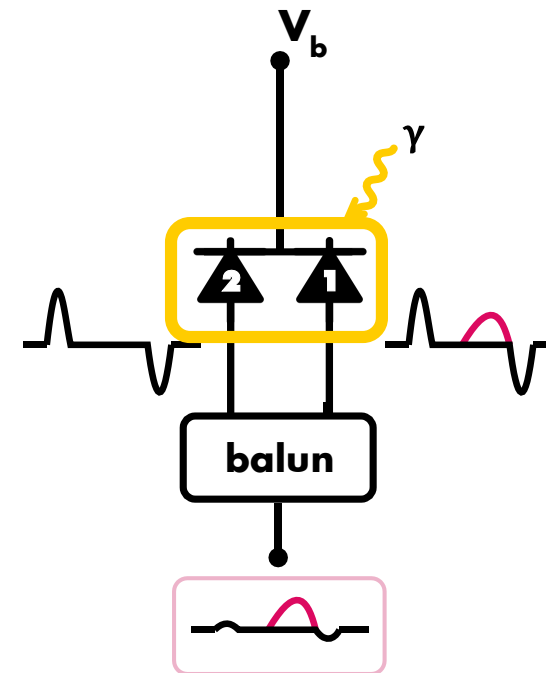
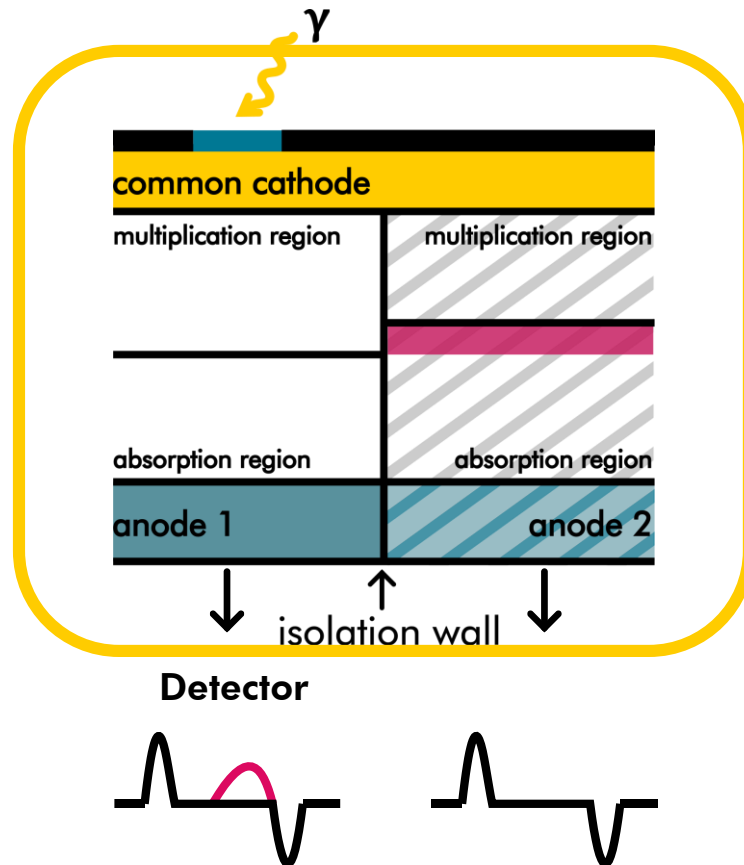
Dual-Anode SPAD (DA-SPAD)



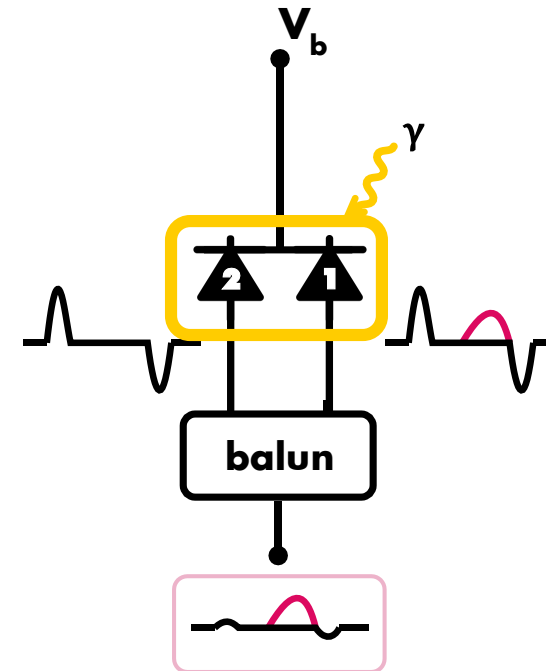
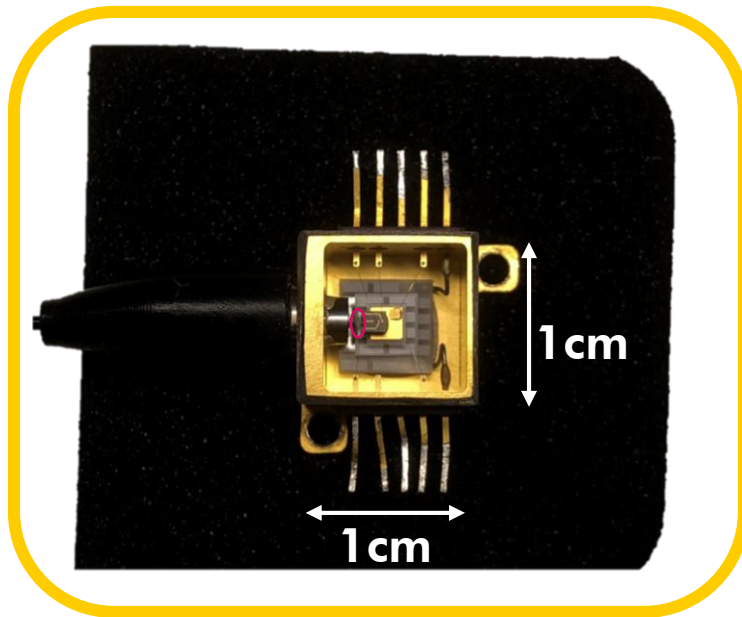
Dual-Anode SPAD (DA-SPAD)



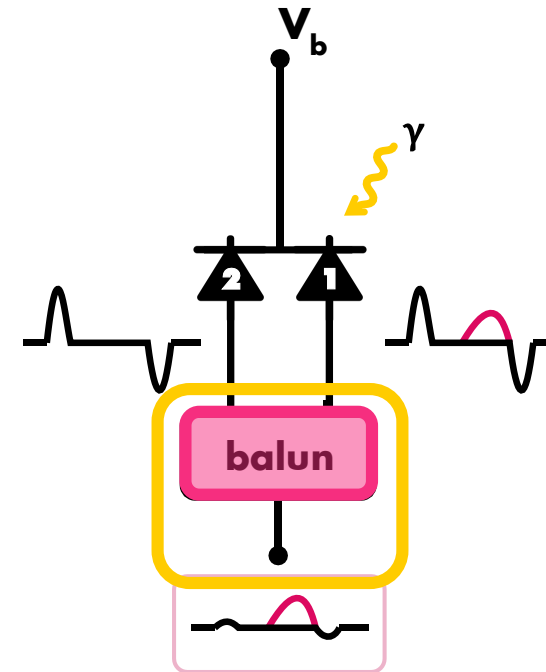
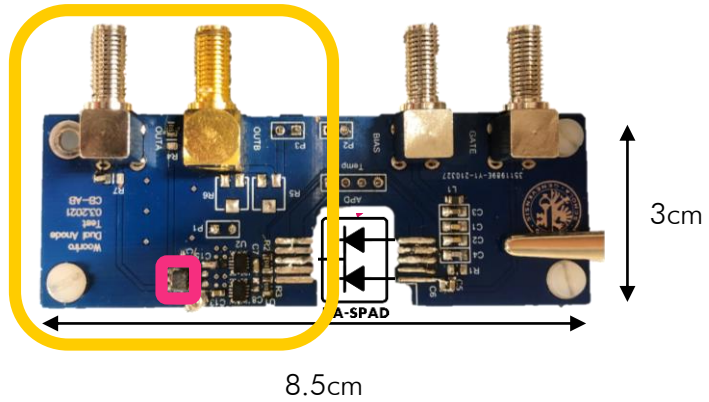
Dual-Anode SPAD (DA-SPAD)



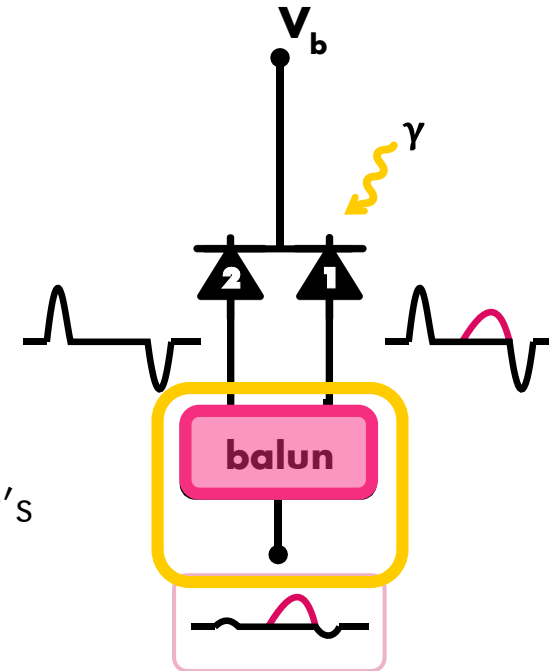
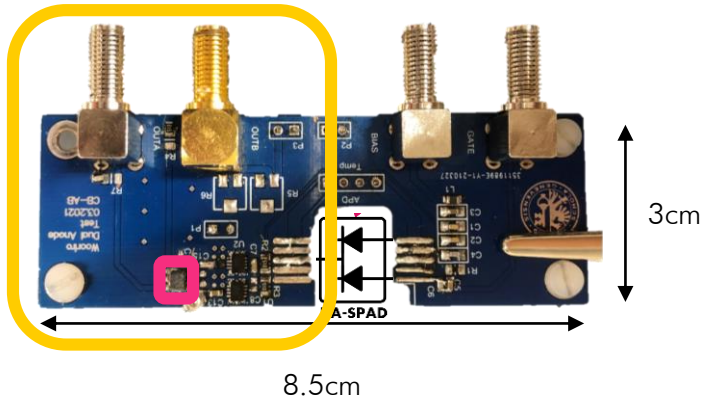
Dual-Anode SPAD (DA-SPAD)



My Goal?



My Goal?



- **Reduce mismatch** between the “dummy”s and detector’s CR with appropriate **electronics**.
- **Optimize** set up to be used in **QKD scenario**.

Thank you!

----- QUESTION SLIDES -----

Photon Detection Efficiency

Probability that a photon impinging on the active area of the detector succeeds in triggering an avalanche current that can be detected by the electronics.

$$PDE = \int_0^{x_{end}} (1 - R) \eta_{abs}(x) P_{col}(x) P_{trig}(x) dx$$

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Diagram illustrating the components of the Photon Detection Efficiency (PDE) equation:

- $(1 - R)$: Reflection Coefficient
- $\eta_{abs}(x)$: Absorption Probability Density
- $P_{col}(x)$: Collection Probability
- $P_{trig}(x)$: Triggering Probability

Photon Detection Efficiency

$$PDE = \int_0^{x_{end}} (1 - R) \boxed{\eta_{abs}(x)} P_{col}(x) P_{trig}(x) dx$$

Absorption Probability
Density

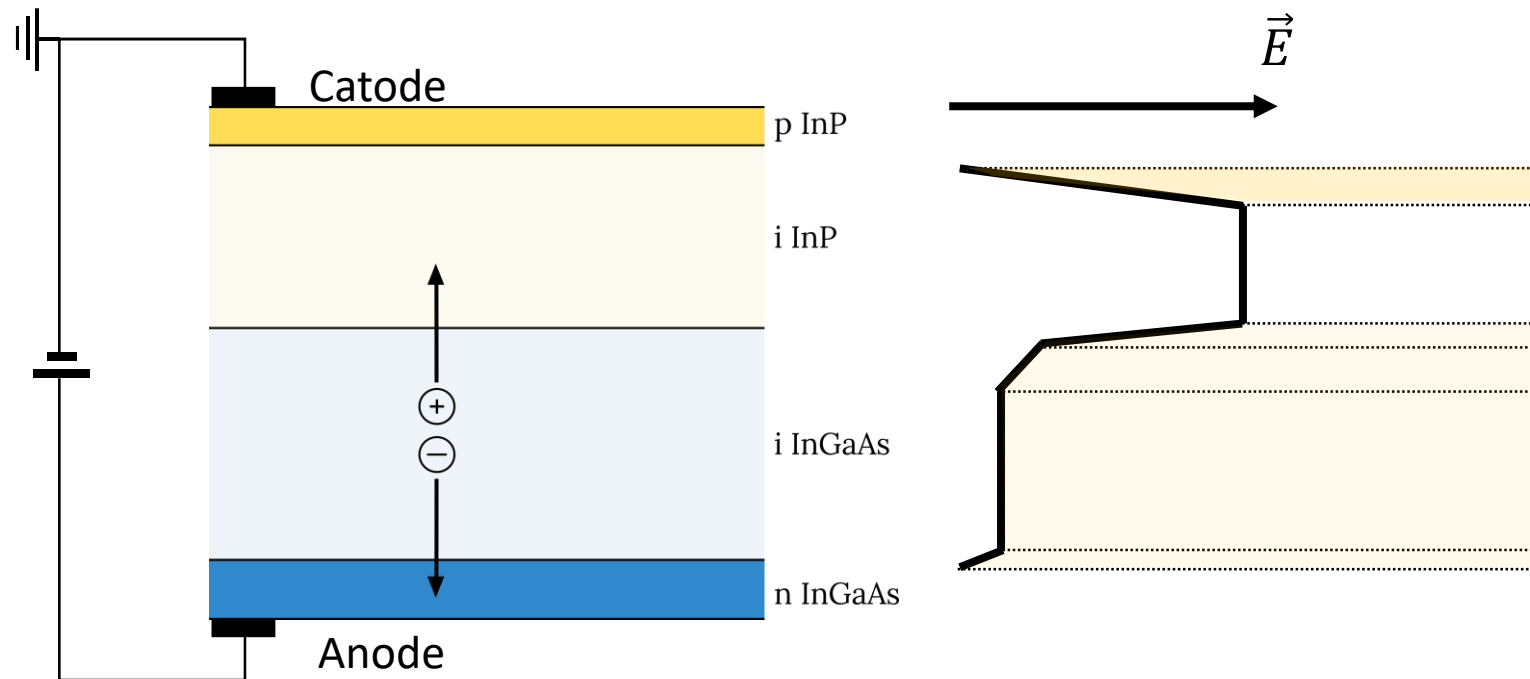
$$\boxed{\eta_{abs}(x)} = \boxed{\alpha} e^{-\alpha x}$$

λ dependent

Photon Detection Efficiency

$$PDE = \int_0^{x_{end}} (1 - R) \eta_{abs}(x) \boxed{P_{col}(x)} P_{trig}(x) dx$$

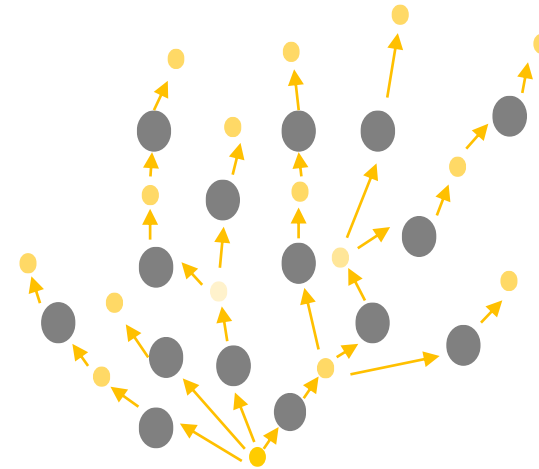
Collection Probability



Photon Detection Efficiency

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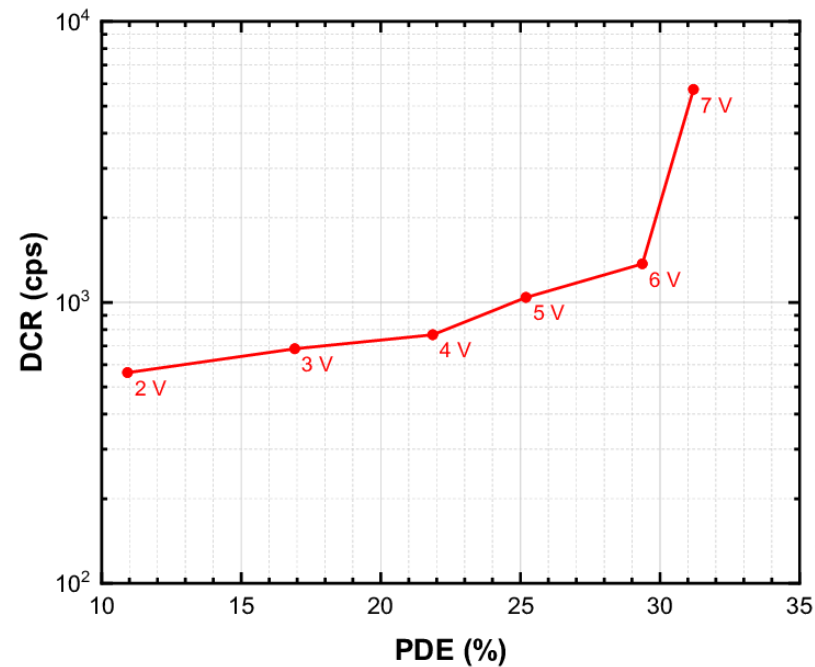
Triggering Probability



Photon Detection Efficiency

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Triggering Probability



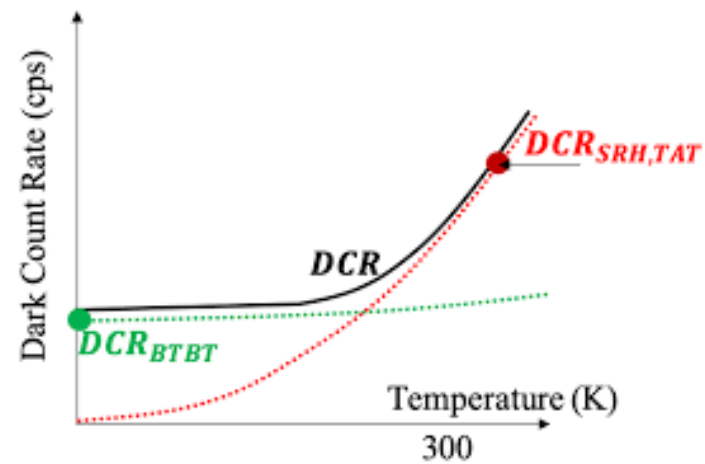
Signorelli, Fabio & Telesca, Fabio & Conca, Enrico & Frera, Adriano & Ruggeri, Alessandro & Giudice, Andrea & Tosi, Alberto. (2021). Low-Noise InGaAs/InP Single-Photon Avalanche Diodes for Fiber-Based and Free-Space Applications. IEEE Journal of Selected Topics in Quantum Electronics. PP. 1-1. 10.1109/JSTQE.2021.3104962.

Dark Count Rate

$$DCR = \frac{\text{average number of dark pulses}}{\text{unit time}}$$

Shockley-Read-Hall (SRH)
Mechanism

Band to Band Tunneling
(BBT)

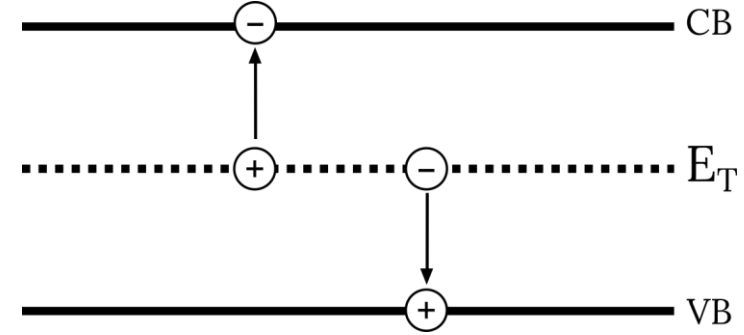


Dark Count Rate

Shockley-Read-Hall (SRH)
Mechanism



Dominant @ Room Temperature

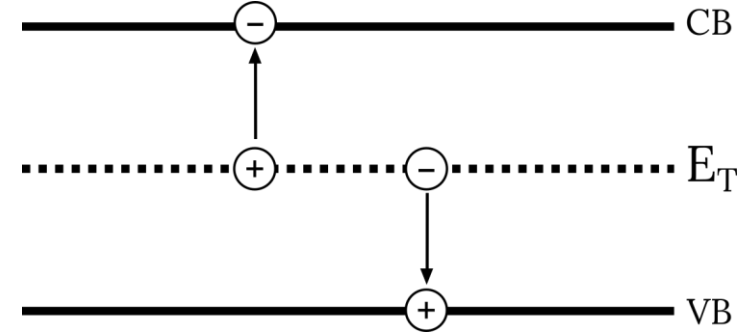


Dark Count Rate

Shockley-Read-Hall (SRH)
Mechanism



Dominant @ Room Temperature



$$\propto N_{trap}$$



Volume Dependent



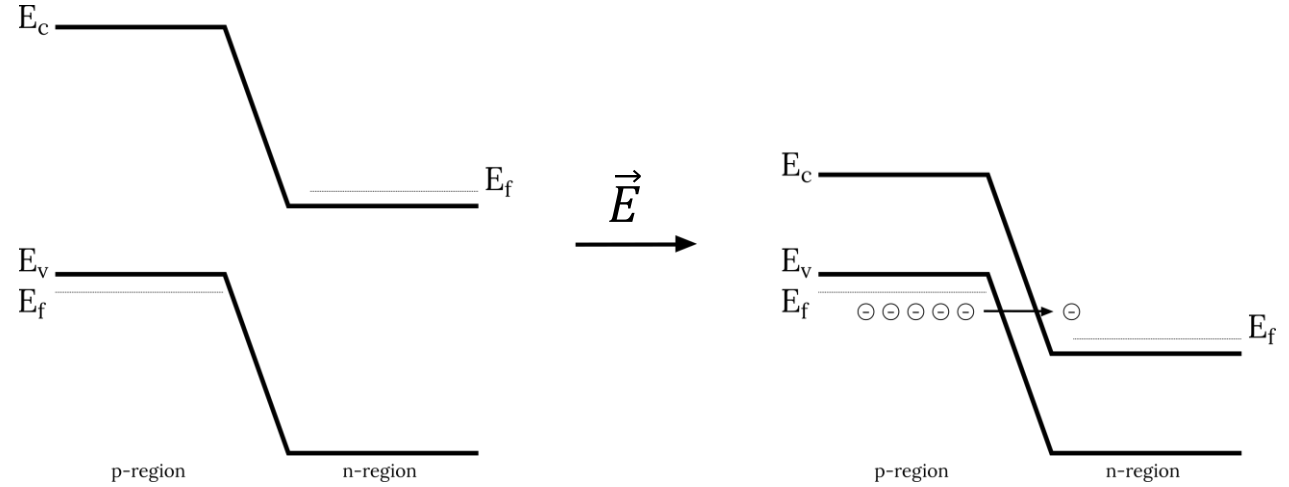
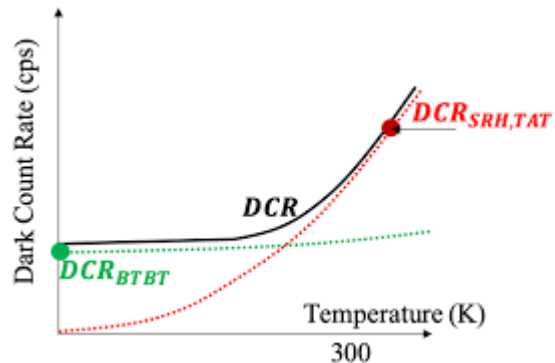
Affected by fabrication
process & initial quality of
the material

Dark Count Rate

Band to Band Tunneling (BBT)



Dominant @ Low Temperature



- Weak Dependence on T
- Strong Dependence on $\vec{E}$



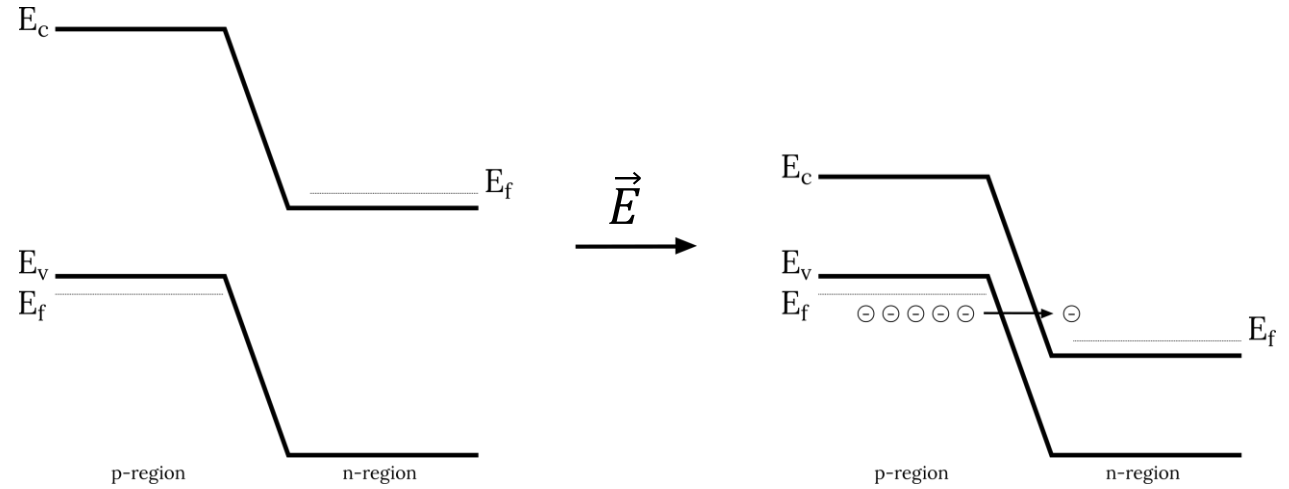
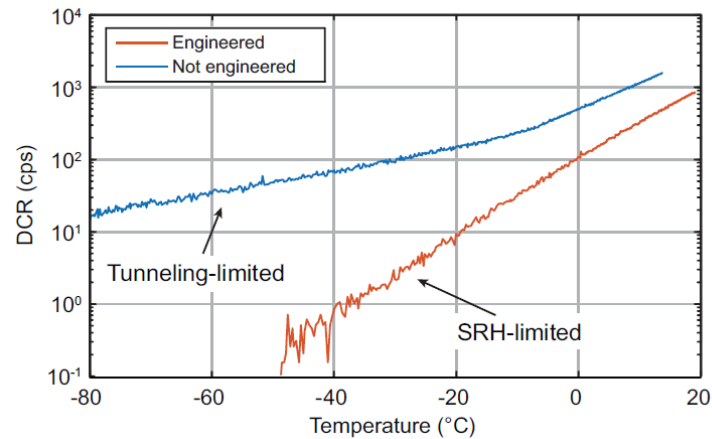
Improved with proper design of detector

Dark Count Rate

Band to Band Tunneling (BBT)



Dominant @ Low Temperature



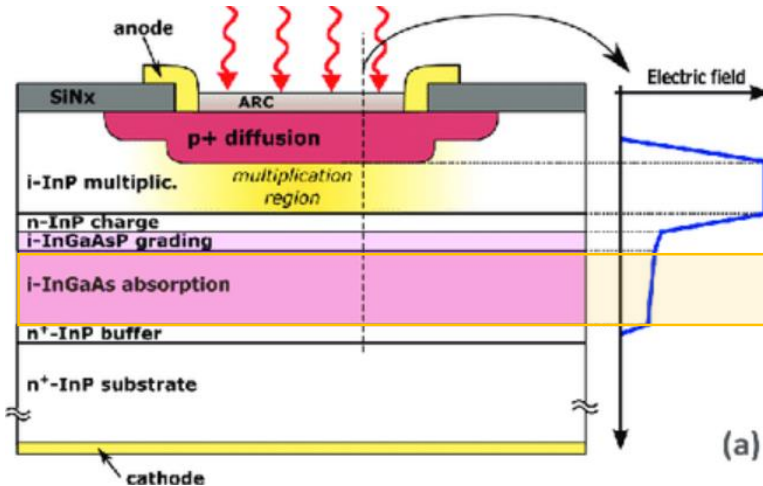
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Improved with proper design of detector

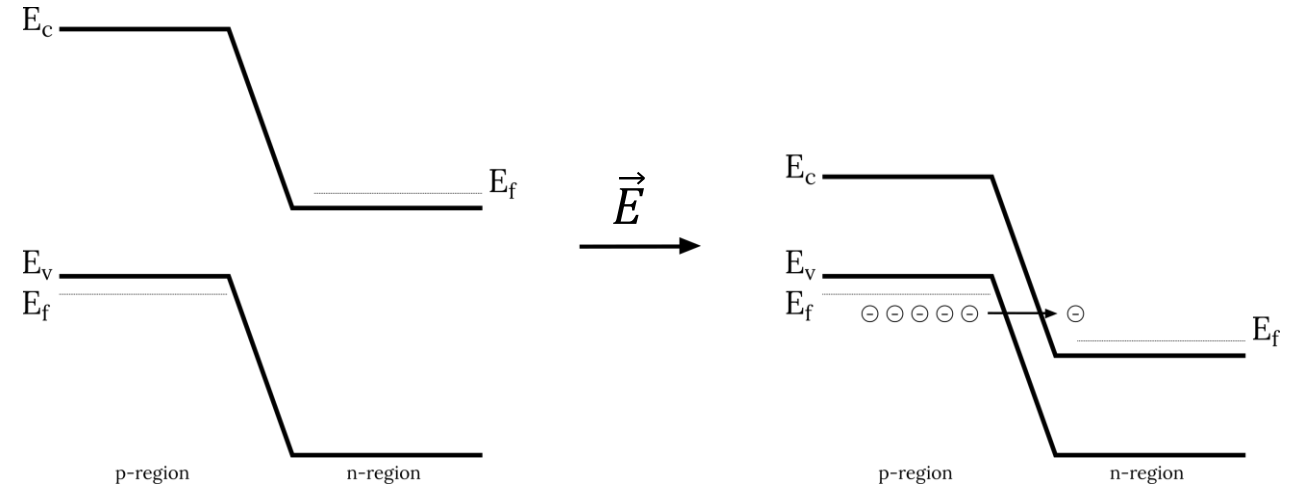
Dark Count Rate

Band to Band Tunneling (BBT)



Separate Absorption, Charge, and Multiplication (SACM) structure

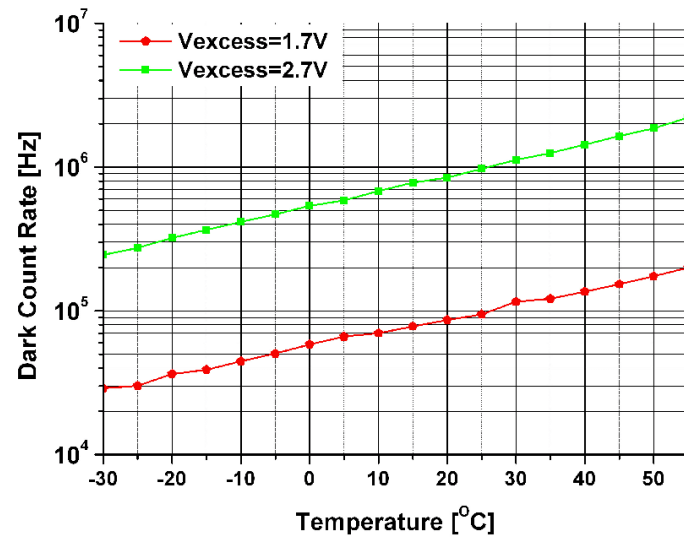
Acerbi, Fabio & Perenzoni, Matteo. (2018). High Sensitivity Photodetector for Photon-Counting Applications. 10.5772/intechopen.71940.



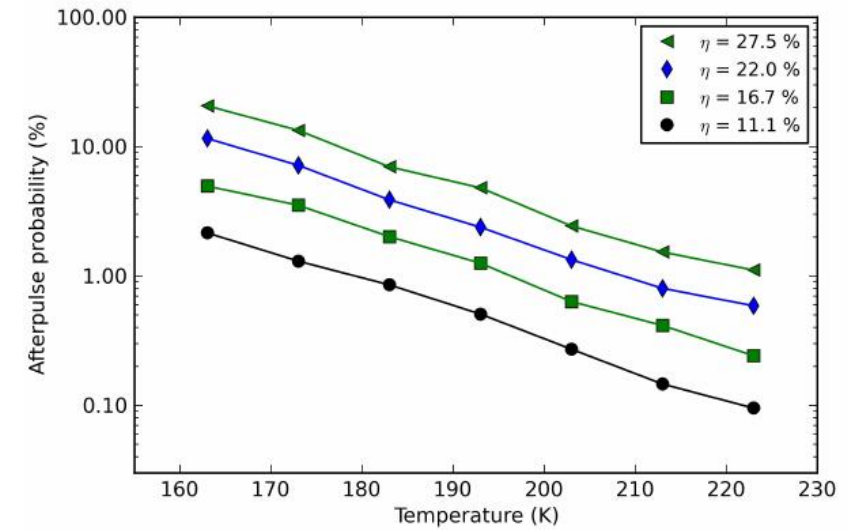
Reduce $\vec{E}$ on
absorption layer
to prevent BBT

- Weak Dependence on T
- Strong Dependence on $\vec{E}$

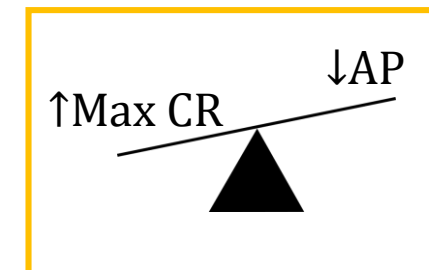
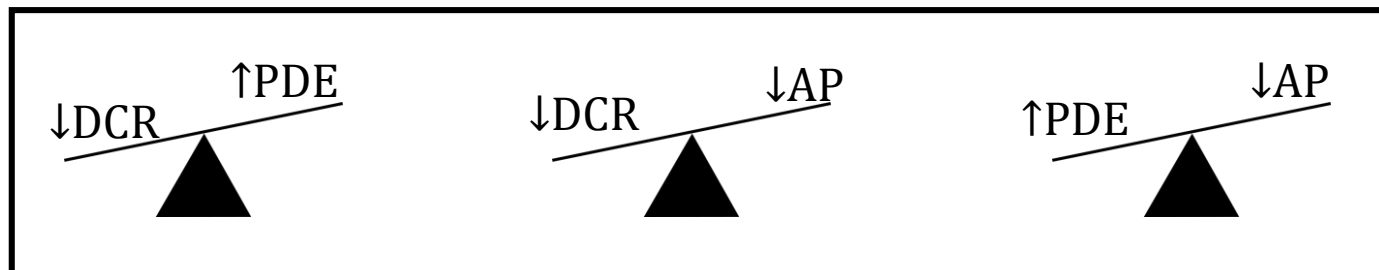
Improved with proper design of detector



Niclass, Cristiano & Gersbach, Marek & Henderson, Robert & Grant, Lindsay & Charbon, E.. (2007). A 130-nm CMOS single-photon avalanche diode. Proceedings of SPIE - The International Society for Optical Engineering. 6766. 10.1117/12.728878.

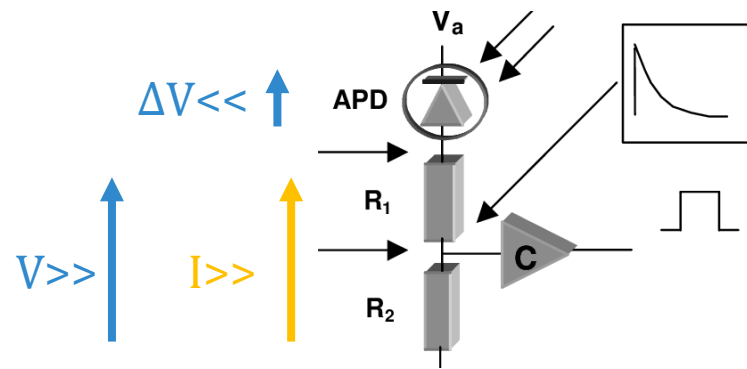


Korzh, Boris & Zbinden, Hugo. (2014). Low temperature performance of free-running InGaAs/InP single-photon negative feedback avalanche diodes. Proceedings of SPIE - The International Society for Optical Engineering. 9114. 10.1117/12.2050487.



Quenching Electronics

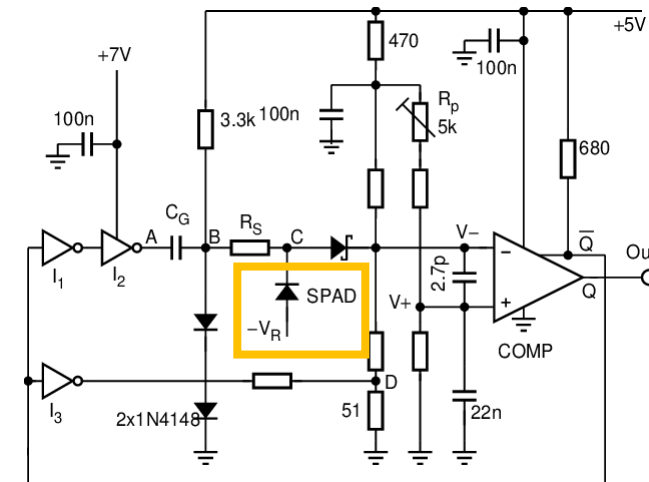
Passive Quenching Circuit.



Phelan, Don & Jackson, Carl & Redfern, R. & Morrison, Alan & Mathewson, Alan. (2002). Geiger mode avalanche photodiodes for microarray systems. Proc SPIE. 10.1117/12.472068.

Avalanche spontaneously quenched by high resistor

Active Quenching Circuit.



Stipčević, Mario. (2009). Active quenching circuit for single-photon detection with Geiger mode avalanche photodiodes. Applied optics. 48. 1705-14. 10.1364/AO.48.001705.

Fast disc. electronics detects avalanche $\rightarrow$ lowers V_b below V_{br} for a given "hold-off" time